Triple Inverter with Open Drain Outputs

The NL37WZ06 is a high performance triple inverter with open drain outputs operating from a 2.3 to 5.5 V supply.

The internal circuit is composed of multiple stages, including an open drain output which provides the capability to set output switching level. This allows the NL37WZ06 to be used to interface 5 V circuits to circuits of any voltage between V_{CC} and 7 V using an external resistor and power supply.

- Extremely High Speed: tpD 2.5 ns (typical) at $V_{CC} = 5 \text{ V}$
- Designed for 2.3 V to 5.5 V V_{CC} Operation
- Over Voltage Tolerant Inputs
- $\bullet\,$ LVTTL Compatible Interface Capability with 5 V TTL Logic with V_{CC} = 3 V
- LVCMOS Compatible
- 24 mA Output Sink Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72

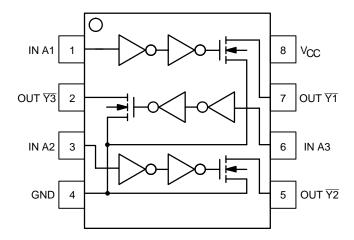


Figure 1. Pinout (Top View)

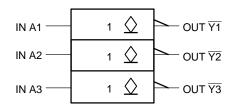


Figure 2. Logic Symbol



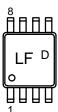
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US8 US SUFFIX CASE 493



MARKING

LF = Device Code D = Date Code

PIN ASSIGNMENT

1	IN A1
2	OUT Y 3
3	IN A2
4	GND
5	OUT Y2
6	IN A3
7	OUT Y1
8	Vcc

FUNCTION TABLE

A Input	₹ Output
L	Z
H	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
VCC	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		-0.5 to +7.0	V
VO	DC Output Voltage		-0.5 to +7.0	V
liK	DC Input Diode Current	V _I < GND	-50	mA
lok	DC Output Diode Current	V _O < GND	-50	mA
IO	DC Output Sink Current		±50	mA
ICC	DC Supply Current per Supply Pin		±100	mA
IGND	DC Ground Current per Ground Pin		±100	mA
TSTG	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature under Bias		+150	°C
θЈА	Thermal Resistance	(Note 1)	250	°C/W
PD	Power Dissipation in Still Air at 85°C		250	mW
MSL	Moisture Sensitivity		Level 1	
FR	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
VESD	_	man Body Model (Note 2) Machine Model (Note 3) ed Device Model (Note 4)	> 2000 > 200 N/A	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
VCC	Supply Voltage	Operating Data Retention Only	2.3 1.5	5.5 5.5	V
٧ı	Input Voltage	(Note 5)	0	5.5	V
٧o	Output Voltage	(HIGH or LOW State)	0	VCC	V
T _A	Operating Free–Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

5. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

			VCC	T _A = 25°C		-40°C ≤ 1	Γ _A ≤ 85°C		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
VIH	High-Level Input Voltage		2.3 to 5.5	0.7 V _{CC}			0.7 V _{CC}		V
VIL	Low-Level Input Voltage		2.3 to 5.5			0.3 V _C C		0.3 V _{CC}	V
ILKG	Z–State Output Leakage Current	$V_{IN} = V_{IL}$ $V_{OUT} = V_{CC}$ or GND	2.3 to 5.5			±5.0		±10.0	μА
VOL	Low-Level Output Voltage	I _{OL} = 100 μA	2.3 to 5.5			0.1		0.1	V
	VIN = VIH or VIL	I _{OL} = 8 mA	2.3		0.22	0.3		0.3	i
		I _{OL} = 12 mA	2.7		0.22	0.4		0.4	i
		I _{OL} = 16 mA	3.0		0.28	0.4		0.4	i
		I _{OL} = 24 mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} or V _{OUT} = V _{CC} or GND	0 to 5.5			±0.1		±1.0	μΑ
IOFF	Power Off–Output Leakage Current	V _{OUT} = 5.5 V	0			1.0		10	μА
ICC	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		10	μΑ

AC ELECTRICAL CHARACTERISTICS $t_R=t_F$ = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

				T _A = 25°C		-40°C ≤ 1			
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
tPZL	Propagation Delay	$R_{L} = R_{1} = 500 \Omega, C_{L} = 30 pF$	2.5 ± 0.2	0.8	3.0	4.0	0.8	4.1	ns
	(Figure 3 and 4)	$R_{L} = R_{1} = 500 \Omega, C_{L} = 50 pF$	3.3 ± 0.3	0.8	2.4	3.2	0.8	3.7	
		$R_{L} = R_{1} = 500 \Omega, C_{L} = 50 pF$	5.0 ± 0.5	0.5	2.4	3.0	0.5	3.5	
tPLZ	Propagation Delay	$R_{L} = R_{1} = 500 \Omega, C_{L} = 30 pF$	2.5 ± 0.2	0.8	2.5	4.0	0.8	4.1	ns
	(Figure 3 and 4)	$R_{L} = R_{1} = 500 \Omega, C_{L} = 50 pF$	3.3 ± 0.3	0.8	2.1	3.2	0.8	3.7	
		$R_{L} = R_1 = 500 \Omega, C_L = 50 pF$	5.0 ± 0.5	0.5	1.2	3.0	0.5	3.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	2.5	pF
COUT	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.0	pF
C _{PD}	Power Dissipation Capacitance (Note 6)	10 MHz, V_{CC} = 5.5 V, V_I = 0 V or V_{CC}	4.0	pF

^{6.} CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

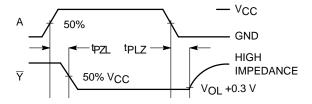
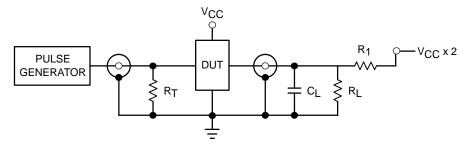


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

DEVICE ORDERING INFORMATION

	Device Nomenclature							
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Package Type	Tape and Reel Size
NL37WZ06US	NL	3	7	WZ	06	US	US8	178 mm (7") 3000 Unit

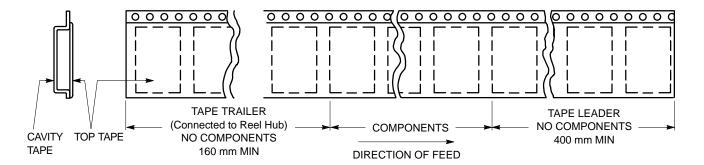


Figure 5. Tape Ends for Finished Goods

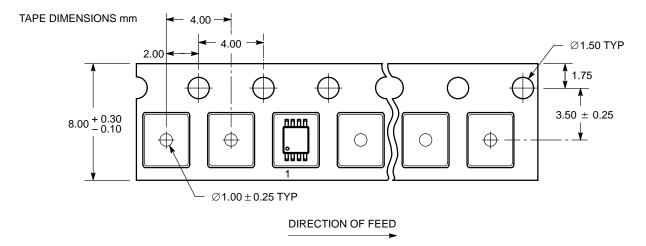


Figure 6. US8 Reel Configuration/Orientation

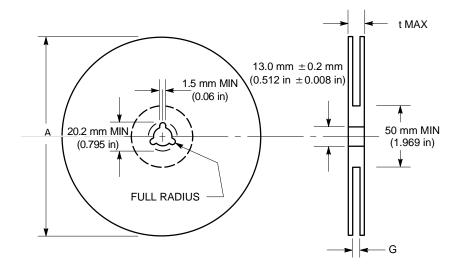


Figure 7. Reel Dimensions

REEL DIMENSIONS

Tape Size	T and R Suffix	A Max	G	t Max
8 mm	US	178 mm (7 in)	8.4 mm, + 1.5 mm, -0.0 (0.33 in + 0.059 in, -0.00)	14.4 mm (0.56 in)

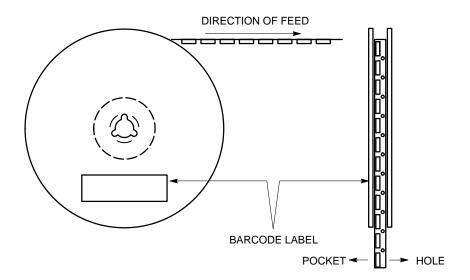
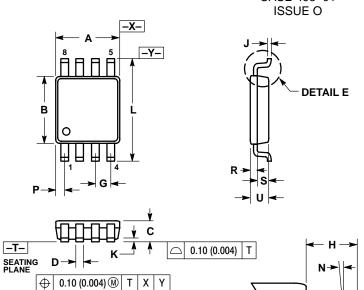


Figure 8. Reel Winding Direction

PACKAGE DIMENSIONS

US8 **US SUFFIX** CASE 493-01





R 0.10 TYP

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS

 3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE.

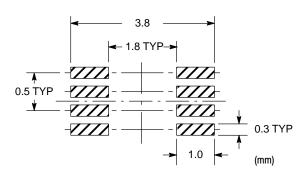
 4. DIMENSION "B" DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION. INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER SIDE.

 5. LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM. (300-800 INCH).

- INCH).

 6. ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 (0.0002").

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
С	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
Н	0.40	REF	0.016	REF	
J	0.10	0.18	0.004	0.007	
K	0.00	0.10	0.000	0.004	
L	3.00	3.20	0.118	0.126	
M	0 °	6 °	0 °	6°	
N	5°	10 °	5 °	10 °	
P	0.28	0.44	0.011	0.017	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024	0.031	
٧	0.12	BSC	0.00	BSC	



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